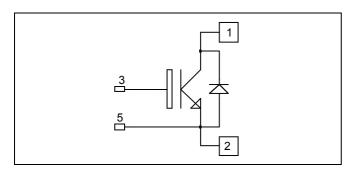


## Single switch Trench + Field Stop IGBT3 Power Module

$$V_{CES} = 1700V$$
  
 $I_{C} = 600A$  @  $Tc = 80$ °C



#### **Application**

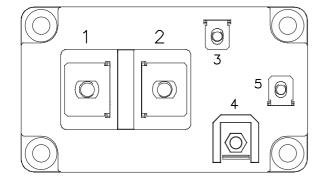
- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

#### **Features**

- Trench + Field Stop IGBT3 Technology
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 20 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- M6 connectors for power
- M4 connectors for signal
- High level of integration

#### **Benefits**

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T<sub>C</sub> of V<sub>CEsat</sub>
- RoHS Compliant



### Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{CES}$	Collector - Emitter Breakdown Voltage		1700	V
$I_{\mathrm{C}}$	Continuous Collector Current	$T_C = 25^{\circ}C$	1100	
	Continuous Conector Current	$T_C = 80$ °C	600	A
$I_{CM}$	Pulsed Collector Current	$T_C = 25^{\circ}C$	1200	
$V_{GE}$	Gate – Emitter Voltage		±20	V
$P_{D}$	Maximum Power Dissipation	$T_C = 25$ °C	2900	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125^{\circ}C$	1200A@1600V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

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1 - 6



## All ratings @ $T_j = 25$ °C unless otherwise specified

### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$I_{CES}$	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1700V$				5	mA
V <sub>CE(sat)</sub>	Collector Emitter saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C		2.0	2.4	V
		$I_{\rm C} = 600 {\rm A}$ $T_{\rm j} = 125 {\rm ^{\circ}C}$		2.4		v	
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$ , $I_C = 24 \text{ mA}$		5.2	5.8	6.4	V
$I_{GES}$	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

**Dynamic Characteristics** 

·	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V, V_{CE} = 25V$			51		nF
$C_{res}$	Reverse Transfer Capacitance	f = 1MHz			1.8		111
$Q_{G}$	Gate charge	V <sub>GE</sub> =±15V, I <sub>C</sub> =600A V <sub>CE</sub> =900V			6.8		μС
$T_{d(on)}$	Turn-on Delay Time	Inductive Switchi	ing (25°C)		280		ns
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$			100		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 900V$ $I_{C} = 600A$			850		
$T_{\mathrm{f}}$	Fall Time	$R_G = 2.4\Omega$		150			
$T_{d(on)}$	Turn-on Delay Time		Inductive Switching (125°C)		330		ns
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$ $V_{Bus} = 900V$ $I_{C} = 600A$			100		
$T_{d(off)}$	Turn-off Delay Time				1000		
$T_{\rm f}$	Fall Time	$R_G = 2.4\Omega$	_		230		
Eon	Turn On Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 900V$	$T_j = 125$ °C		200		mJ
$E_{\text{off}}$	Turn Off Energy	$I_C = 600A$ $R_G = 2.4\Omega$	$T_j = 125$ °C		190		111,)
$I_{sc}$	Short Circuit data	$V_{GE} \le 15V$ ; $V_{Bus} = 1000V$ $t_p \le 10 \mu s$ ; $T_i = 125 ^{\circ}C$			2200		A

## Reverse diode ratings and characteristics

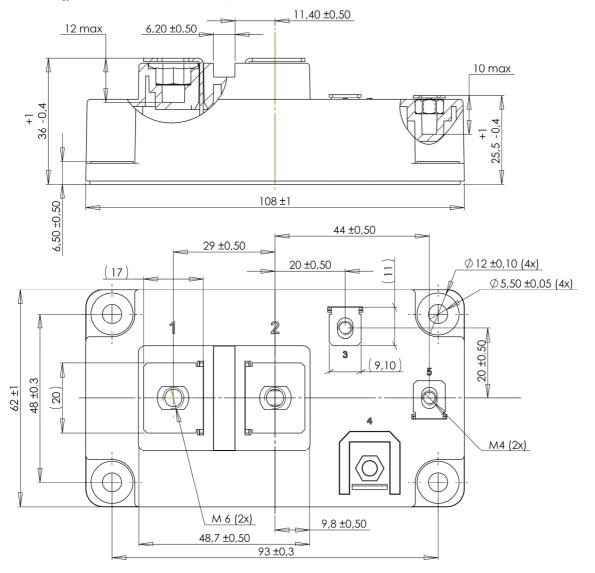
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage			1700			V
$I_{RRM}$	Maximum Reverse Leakage Current	V <sub>R</sub> =1700V	$T_i = 25^{\circ}C$ $T_i = 125^{\circ}C$			750 1000	μΑ
$I_F$	DC forward current		Tc=80°C		600		A
V	Diode Forward Voltage	$I_F = 600A$ $V_{GE} = 0V$	$T_i = 25^{\circ}C$		1.8	2.2	V
$V_{\rm F}$			$T_{i} = 125^{\circ}C$		1.9		] <b>'</b>
E <sub>rr</sub>	Davidea Dagayami Emanari		$T_j = 25$ °C		85		mJ
	Reverse Recovery Energy		$T_j = 125$ °C		145		1113
t <sub>rr</sub>	Davarsa Dagayary Tima	$I_F = 600A$ $V_R = 900V$	$T_j = 25$ °C		450		200
	Reverse Recovery Time	$di/dt = 5200A/\mu s$	$T_j = 125$ °C		600		ns
Q <sub>rr</sub>	Reverse Recovery Charge		$T_j = 25$ °C		150		μС
	Reverse Recovery Charge		$T_{j} = 125^{\circ}C$		250		μС



## Thermal and package characteristics

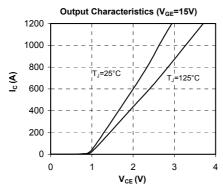
Symbol	Characteristic		Min	Тур	Max	Unit	
$R_{\text{thJC}}$	Junction to Case Thermal Resistance	IGBT			0.044	°C/W	
		Diode			0.065		
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz		4000			V	
$T_{J}$	Operating junction temperature range		-40		150		
$T_{STG}$	Storage Temperature Range		-40		125	°C	
$T_{\rm C}$	Operating Case Temperature	ase Temperature -40			125		
Torque	Mounting torque	M4	1		2	N.m	
		M6	3		5	111.111	
Wt	Package Weight				350	g	

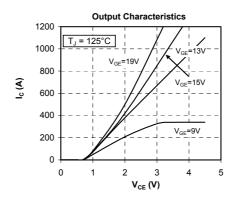
### **D4 Package outline** (dimensions in mm)

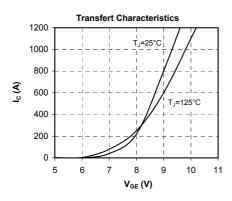


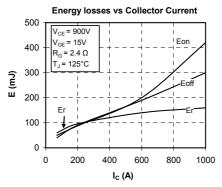


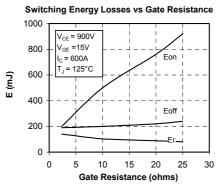
### **Typical Performance Curve**

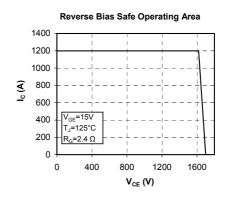


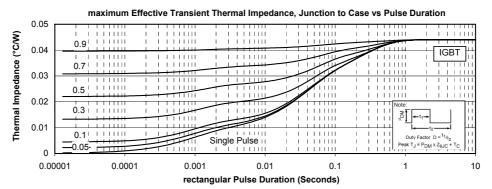




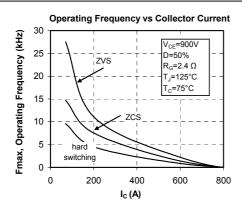


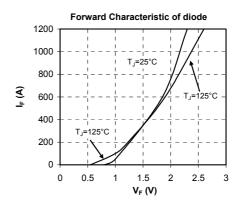


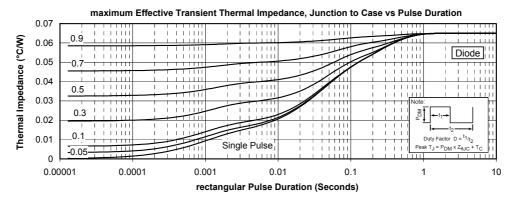














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